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Kind regards,

Team Nexperia



# PIMZ2; PUMZ2 NPN/PNP general-purpose double transistors Rev. 06 — 17 November 2009

Product data sheet

# **Product profile**

#### 1.1 General description

NPN/PNP general-purpose double transistors.

Table 1. **Product overview** 

Type number	Package		Configuration
	NXP	JEITA	
PIMZ2	SOT457	SC-74	NPN/PNP double transistors
PUMZ2	SOT363	SC-88	NPN/PNP double transistors

#### 1.2 Features

- Simplified circuit design
- Reduced component count
- Reduced pick and place costs

#### 1.3 Applications

■ General-purpose switching and amplification

#### 1.4 Quick reference data

Table 2. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$V_{CEO}$	collector-emitter voltage	open base	-	-	50	V
I <sub>C</sub>	collector current (DC)		-	-	150	mA



# 2. Pinning information

Table 3. Pinning

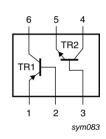
Pin	Description	Simplified outline	Symbol
PIMZ2 (S	SOT457)		
1	collector TR2	D- D- D.	
2	emitter TR2	6   5   4	6 5 4
3	collector TR1	0	المراا
4	emitter TR1	<u> </u>	
5	base TR1		TR2
6	base TR2		1 2 3
			sym082

PUMZ2 (SOT363)				
1	emitter TR1			
2	base TR1			
3	base TR2			
4	collector TR2			

emitter TR2

collector TR1





# 3. Ordering information

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Table 4. Ordering information

Type number	Package				
	Name	Description	Version		
PIMZ2	SC-74	plastic surface mounted package; 6 leads	SOT457		
PUMZ2	SC-88	plastic surface mounted package; 6 leads	SOT363		

# 4. Marking

Table 5. Marking codes

Type number	Marking code <sup>[1]</sup>
PIMZ2	M6
PUMZ2	GZ*

- [1] \* = -: made in Hong Kong
  - \* = t: made in Malaysia
  - \* = W: made in China

# 5. Limiting values

Table 6. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
Per transis	stor; for the PNP transistor	with negative pola	rity		
$V_{CBO}$	collector-base voltage	open emitter	-	60	V
$V_{CEO}$	collector-emitter voltage	open base	-	50	V
$V_{EBO}$	emitter-base voltage	open collector	-	7	V
I <sub>C</sub>	collector current (DC)		-	150	mA
I <sub>CM</sub>	peak collector current		-	200	mA
$I_{BM}$	peak base current		-	100	mA
P <sub>tot</sub>	total power dissipation	$T_{amb} \le 25  ^{\circ}C$			
	SOT457		[1] -	200	mW
	SOT363		[1] -	180	mW
T <sub>stg</sub>	storage temperature		-65	+150	°C
Tj	junction temperature		-	150	°C
T <sub>amb</sub>	ambient temperature		-65	+150	°C
Per device	)				
P <sub>tot</sub>	total power dissipation	$T_{amb} \le 25  ^{\circ}C$			
	SOT457		<u>[1]</u> -	300	mW
	SOT363		[1] -	300	mW

<sup>[1]</sup> Device mounted on an FR4 printed-circuit board.

# 6. Thermal characteristics

Table 7. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Per trans	istor					
$R_{th(j-a)}$	thermal resistance from junction to ambient	$T_{amb} \le 25  ^{\circ}C$				
	SOT457		[1] -	-	625	K/W
	SOT363		<u>[1]</u> -	-	694	K/W
Per devic	e					
$R_{th(j-a)}$	thermal resistance from junction to ambient	$T_{amb} \le 25  ^{\circ}C$				
	SOT457		[1] -	-	417	K/W
	SOT363		[1] -	-	417	K/W

<sup>[1]</sup> Device mounted on an FR4 printed-circuit board.

# 7. Characteristics

Table 8. Characteristics

T<sub>amb</sub> = 25 °C unless otherwise specified.

	•					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Per trans	sistor; for the PNP transistor	with negative polarity; unless otherwise	specified			
I <sub>CBO</sub>	collector-base cut-off current	$V_{CB} = 60 \text{ V}; I_E = 0 \text{ A}$	-	-	100	nA
		$V_{CB} = 60 \text{ V}; I_E = 0 \text{ A}; T_j = 150 ^{\circ}\text{C}$	-	-	50	μΑ
I <sub>EBO</sub>	emitter-base cut-off current	$V_{EB} = 7 \text{ V}; I_{C} = 0 \text{ A}$	-	-	100	nA
h <sub>FE</sub>	DC current gain	V <sub>CE</sub> = 6 V; I <sub>C</sub> = 1 mA	120	250	560	
TR1 (PN	P)					
V <sub>CEsat</sub>	collector-emitter saturation voltage	$I_C = -50 \text{ mA}; I_B = -5 \text{ mA}$	-	-	-500	mV
f <sub>T</sub>	transition frequency	$I_E = -2 \text{ mA}; V_{CE} = -12 \text{ V}; f = 100 \text{ MHz}$	-	190	-	MHz
C <sub>c</sub>	collector capacitance	$I_E = i_e = 0 \text{ A}; V_{CB} = -12 \text{ V}; f = 1 \text{ MHz}$	-	2.3	5	pF
TR2 (NP	N)					
V <sub>CEsat</sub>	collector-emitter saturation voltage	$I_C = 50 \text{ mA}; I_B = 5 \text{ mA}$	-	-	250	mV
f <sub>T</sub>	transition frequency	$I_E = 2 \text{ mA}; V_{CE} = 12 \text{ V}; f = 100 \text{ MHz}$	100	-	-	MHz
C <sub>c</sub>	collector capacitance	$I_E = i_e = 0 A; V_{CB} = 12 V; f = 1 MHz$	-	-	3	рF

# 8. Package outline

#### Plastic surface-mounted package (TSOP6); 6 leads

**SOT457** 

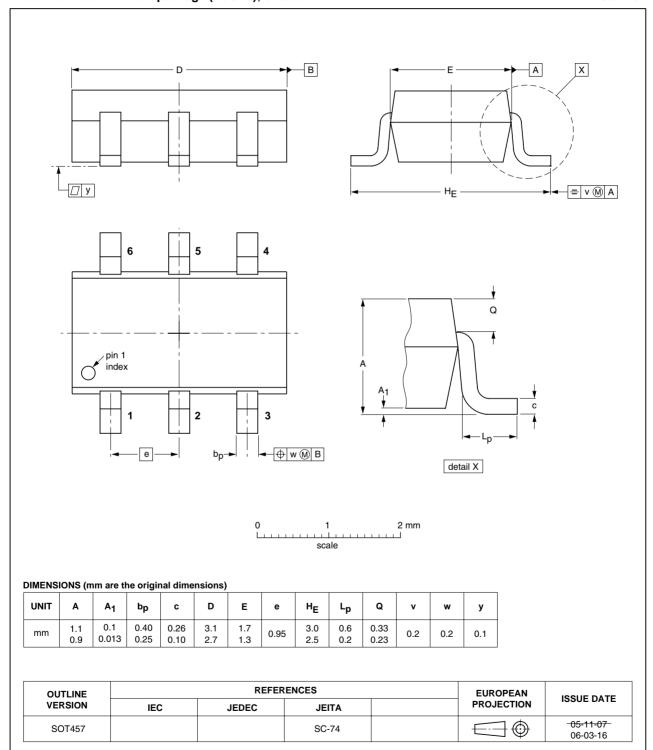


Fig 1. Package outline SOT457 (SC-74)

PIMZ2\_PUMZ2\_6

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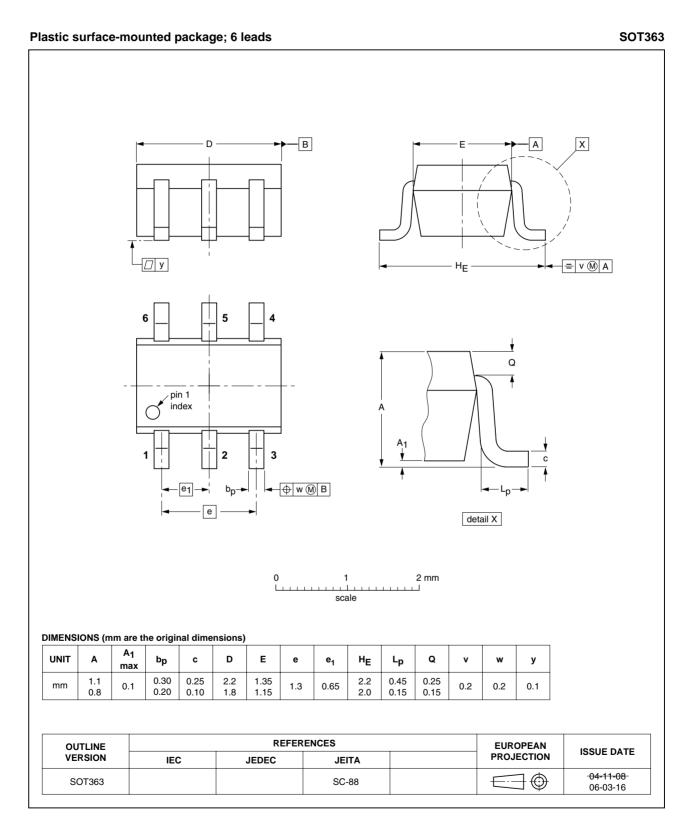


Fig 2. Package outline SOT363 (SC-88)

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# NPN/PNP general-purpose double transistors

# 9. Revision history

Table 9. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
PIMZ2_PUMZ2_6	20091117	Product data sheet	-	PIMZ2_PUMZ2_5
Modifications:	including ne content.  • Table 3 "Pin  • Figure 1 "Pa	neet was changed to reflect to which we legal definitions and disclassing the second section of the second sections and disclassing the section of the secti	aimers. No changes w	
PIMZ2_PUMZ2_5	20041124	Product data sheet	-	PIMZ2_PUMZ2_4
PIMZ2_PUMZ2_4	20031217	Product specification	-	PIMZ2_2
PIMZ2_2	20030714	Product specification	-	PIMZ2_1
PIMZ2_1	20030602	Objective specification	-	-

#### 10. Legal information

#### 10.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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